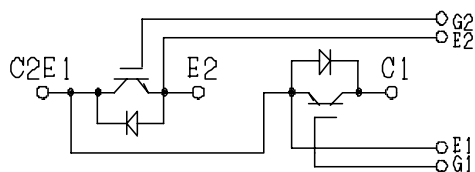
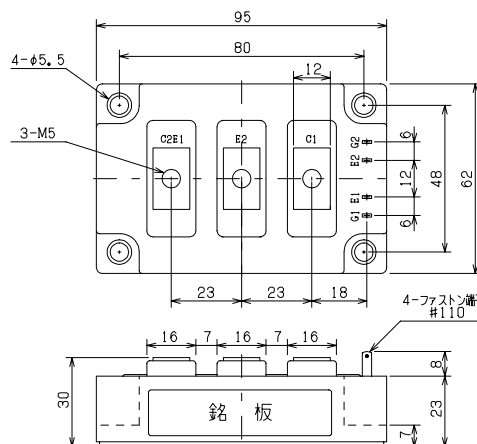


**CIRCUIT**

**OUTLINE DRAWING**


4-fasten- tab No 110

Dimension(mm)

**MAXMUM RATINGS** (Tc=25°C)

Approximate Weight : 430g

| Item                                            | Symbol                    | PDMB300A6       | Unit |
|-------------------------------------------------|---------------------------|-----------------|------|
| Collector-Emitter Voltage                       | V <sub>CES</sub>          | 600             | V    |
| Gate - Emitter Voltage                          | V <sub>GES</sub>          | +/- 20          | V    |
| Collector Current                               | DC                        | I <sub>C</sub>  | A    |
|                                                 | 1 ms                      | I <sub>CP</sub> |      |
| Collector Power Dissipation                     | P <sub>C</sub>            | 1040            | W    |
| Junction Temperature Range                      | T <sub>j</sub>            | -40 to +150     | °C   |
| Storage Temperature Range                       | T <sub>stg</sub>          | -40 to +125     | °C   |
| Isolation Voltage (Terminal to Base AC, 1 min.) | V <sub>ISO</sub>          | 2500            | V    |
| Mounting Torque                                 | Module Base to Heatsink   | 2               | N•m  |
|                                                 | Bus Bar to Main Terminals |                 |      |

**ELECTRICAL CHARACTERISTICS** (Tc=25°C)

| Characteristic                       | Symbol               | Test Condition                                                                                          | Min. | Typ.   | Max. | Unit |
|--------------------------------------|----------------------|---------------------------------------------------------------------------------------------------------|------|--------|------|------|
| Collector-Emitter Cut-Off Current    | I <sub>CES</sub>     | V <sub>CE</sub> =600V, V <sub>GE</sub> =0V                                                              | -    | -      | 3.0  | mA   |
| Gate-Emitter Leakage Current         | I <sub>GES</sub>     | V <sub>GE</sub> =+/- 20V, V <sub>CE</sub> =0V                                                           | -    | -      | 1.0  | μA   |
| Collector-Emitter Saturation Voltage | V <sub>CE(sat)</sub> | I <sub>C</sub> =300A, V <sub>GE</sub> =15V                                                              | -    | 2.1    | 2.6  | V    |
| Gate-Emitter Threshold Voltage       | V <sub>GE(th)</sub>  | V <sub>CE</sub> =5V, I <sub>C</sub> =300mA                                                              | 4.0  | -      | 8.0  | V    |
| Input Capacitance                    | C <sub>ies</sub>     | V <sub>CE</sub> =10V, V <sub>GE</sub> =0V, f=1MHz                                                       | -    | 30,000 | -    | pF   |
| Switching Time                       | Rise Time            | V <sub>CC</sub> = 300V<br>R <sub>L</sub> = 1 ohm<br>R <sub>G</sub> = 2 ohm<br>V <sub>GE</sub> = +/- 15V | -    | 0.2    | 0.4  | μs   |
|                                      | Turn-on Time         |                                                                                                         | -    | 0.4    | 0.75 |      |
|                                      | Fall Time            |                                                                                                         | -    | 0.2    | 0.35 |      |
|                                      | Turn-off Time        |                                                                                                         | -    | 0.6    | 0.8  |      |

**FREE WHEELING DIODES RATINGS & CHARACTERISTICS** (Tc=25°C)

| Item            | Symbol | Rated Value     | Unit |
|-----------------|--------|-----------------|------|
| Forward Current | DC     | I <sub>F</sub>  | A    |
|                 | 1 ms   | I <sub>FM</sub> |      |

| Characteristic        | Symbol          | Test Condition                                             | Min. | Typ. | Max. | Unit |
|-----------------------|-----------------|------------------------------------------------------------|------|------|------|------|
| Peak Forward Voltage  | V <sub>F</sub>  | I <sub>F</sub> =300A, V <sub>GE</sub> =0V                  | -    | 1.9  | 2.4  | V    |
| Reverse Recovery Time | t <sub>rr</sub> | I <sub>F</sub> =300A, V <sub>GE</sub> =-10V, di/dt=300A/μs | -    | 0.15 | 0.25 | μs   |

**THERMAL CHARACTERISTICS**

| Characteristic    | Symbol | Test Condition   | Min. | Typ. | Max. | Unit |
|-------------------|--------|------------------|------|------|------|------|
| Thermal Impedance | IGBT   | Junction to Case | -    | -    | 0.12 | °C/W |
|                   | DIODE  |                  | -    | -    | 0.24 |      |

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Fig.1- Output Characteristics (Typical)

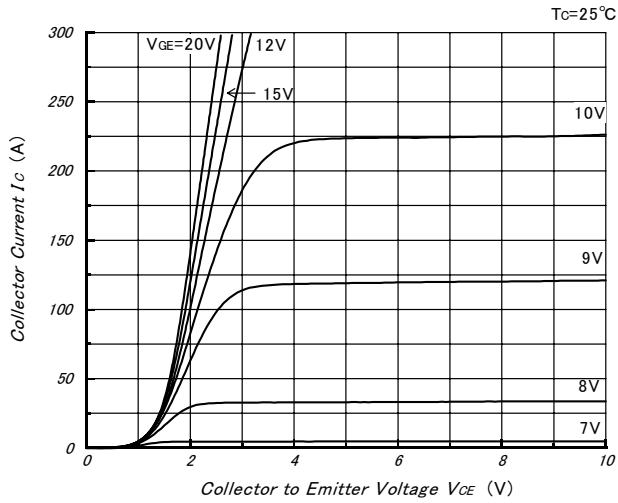


Fig.2- Collector to Emitter On Voltage vs. Gate to Emitter Voltage (Typical)

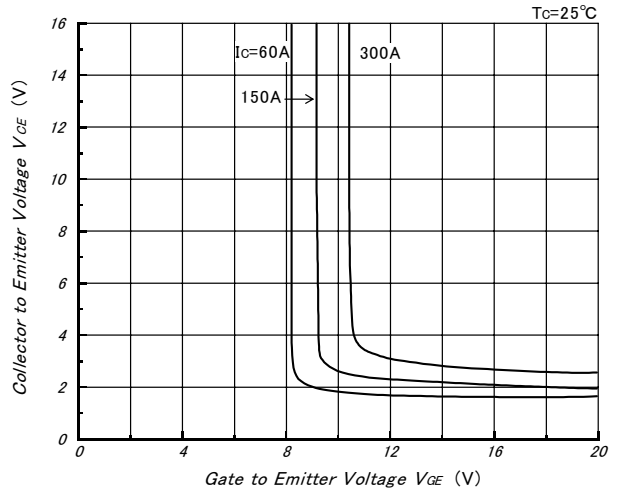


Fig.3- Collector to Emitter On Voltage vs. Gate to Emitter Voltage (Typical)

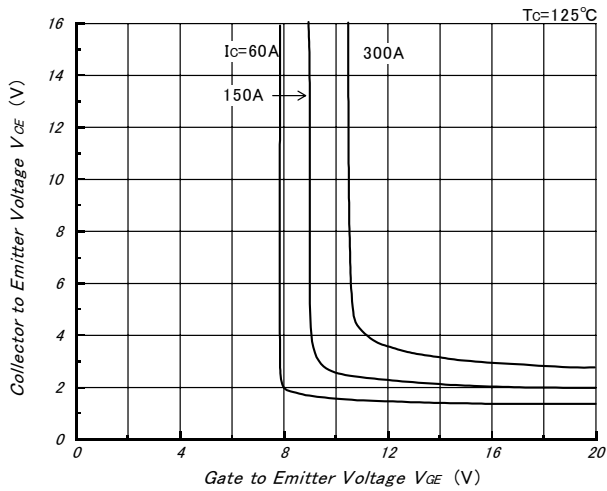


Fig.4- Gate Charge vs. Collector to Emitter Voltage (Typical)

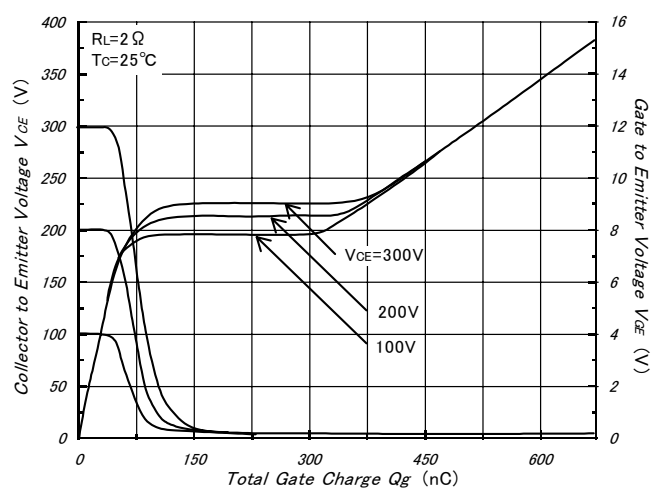


Fig.5- Capacitance vs. Collector to Emitter Voltage (Typical)

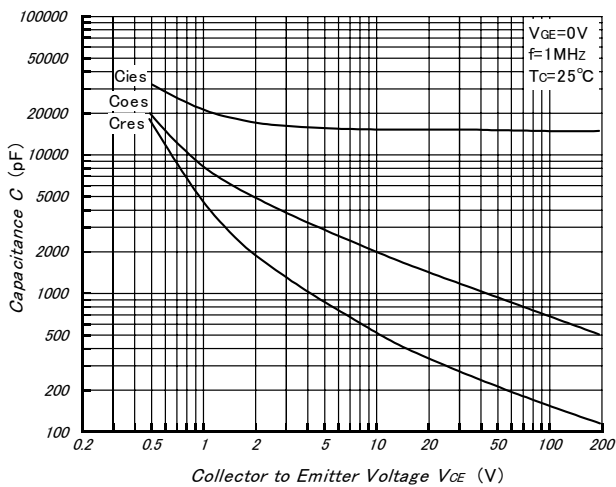
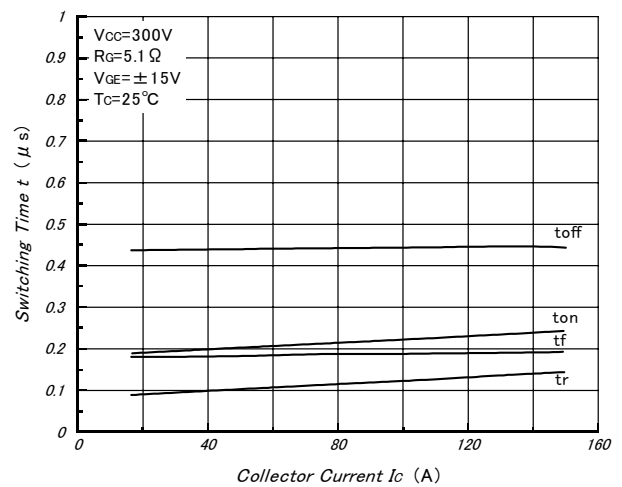


Fig.6- Collector Current vs. Switching Time (Typical)



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Fig.7- Series Gate Impedance vs. Switching Time (Typical)

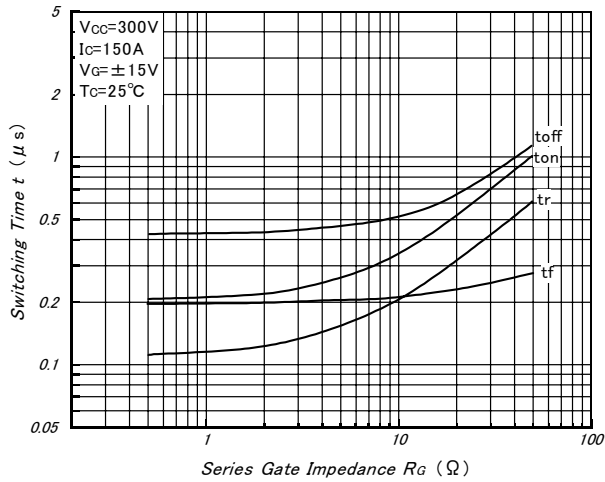


Fig.8- Forward Characteristics of Free Wheeling Diode (Typical)

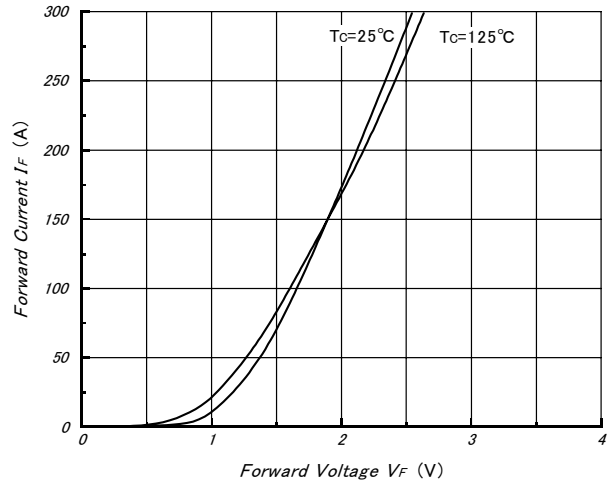


Fig.9- Reverse Recovery Characteristics (Typical)

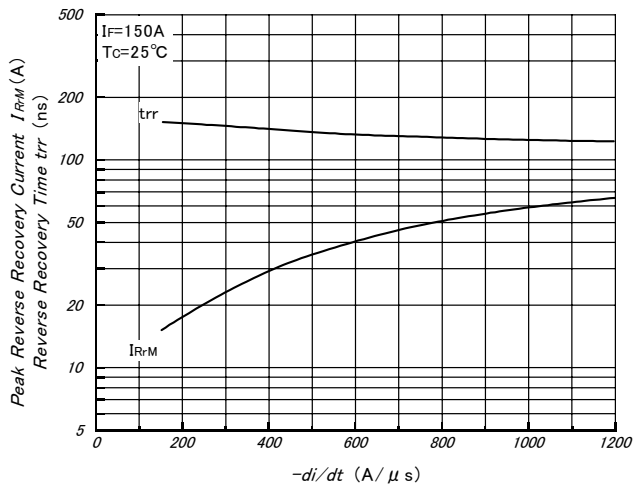


Fig.10- Reverse Bias Safe Operating Area (Typical)

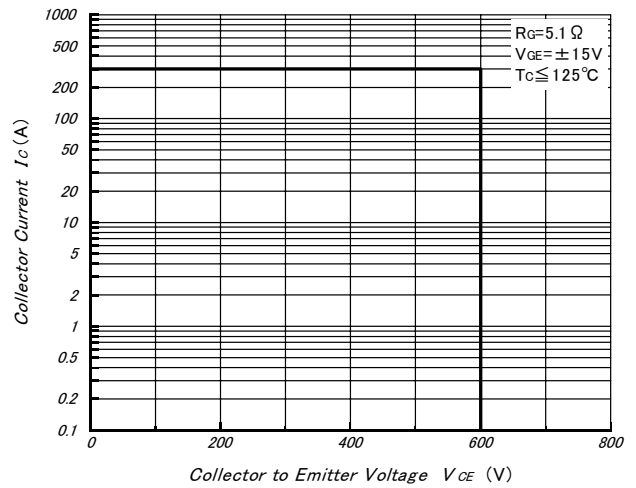


Fig.11- Transient Thermal Impedance

